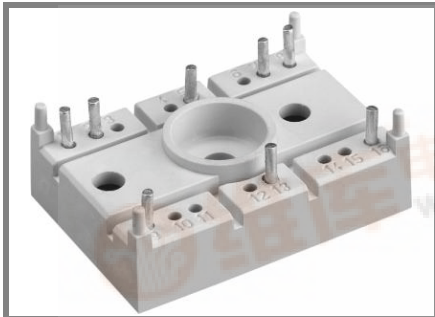


SK 50 GB 065



SEMITOP® 2

Fast IGBT Module

SK 50 GB 065

Preliminary Data

Features

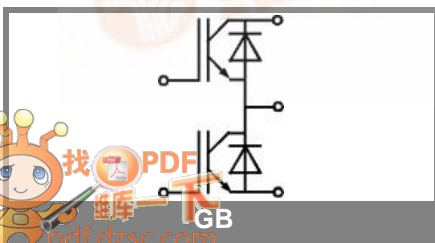
- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- N-channel homogeneous silicon structure (NPT-Non punch-through IGBT)
- Low tail current with low temperature dependence
- Low threshold voltage

Typical Applications

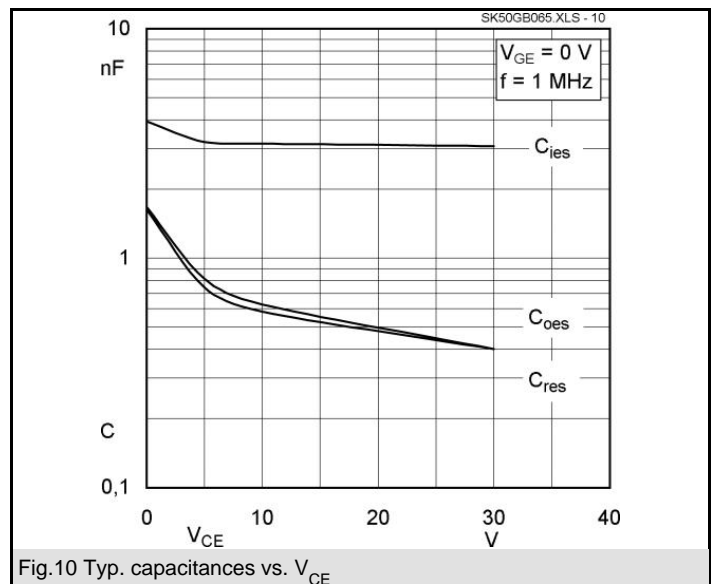
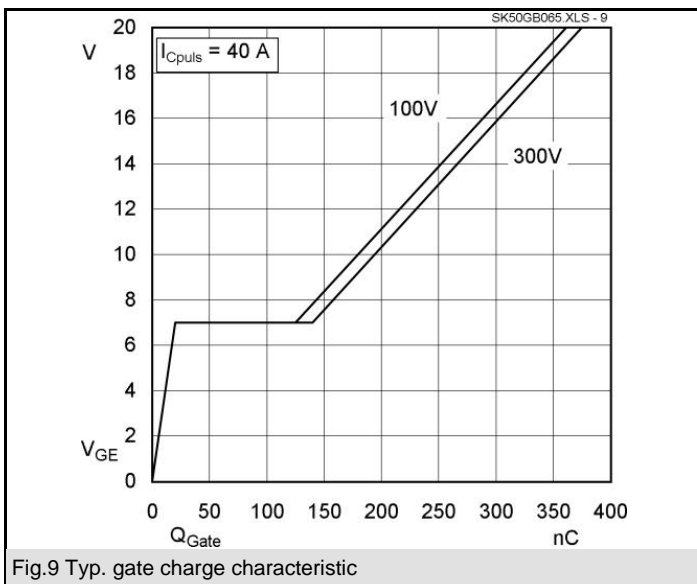
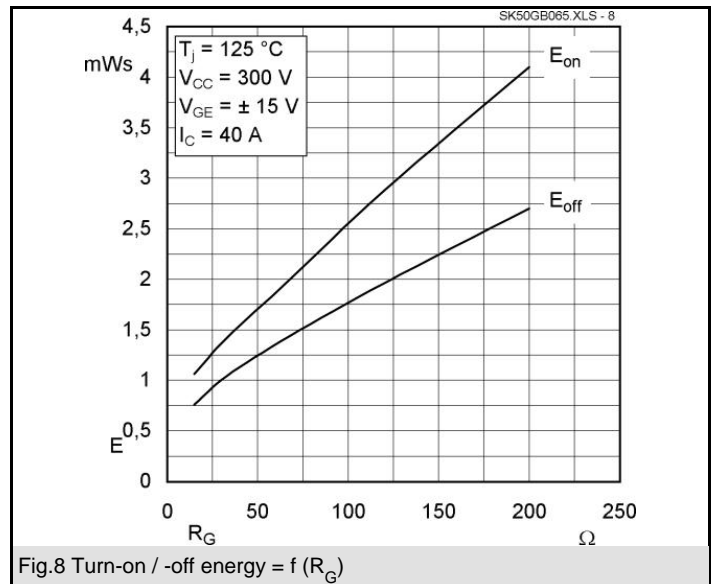
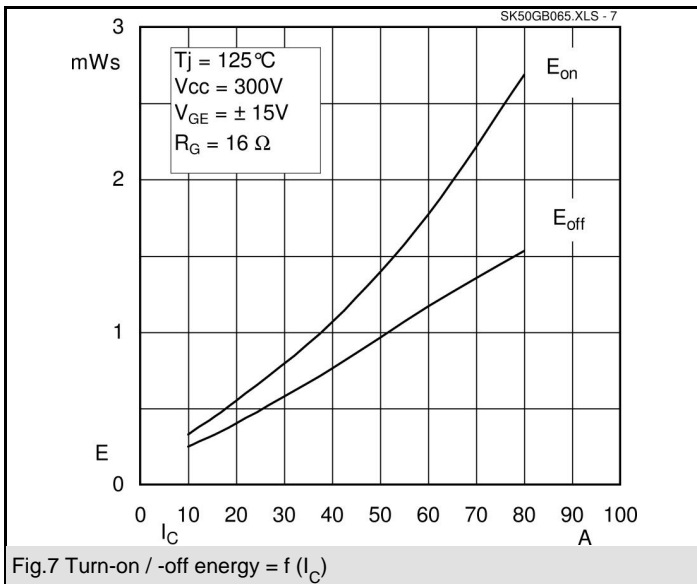
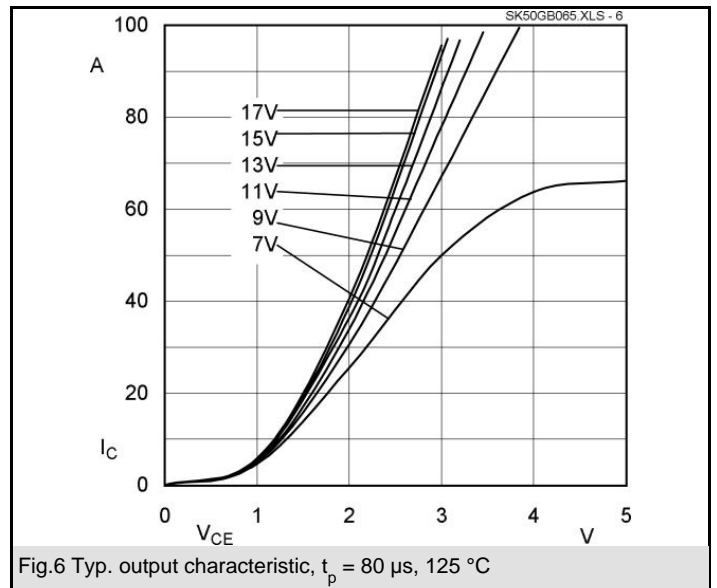
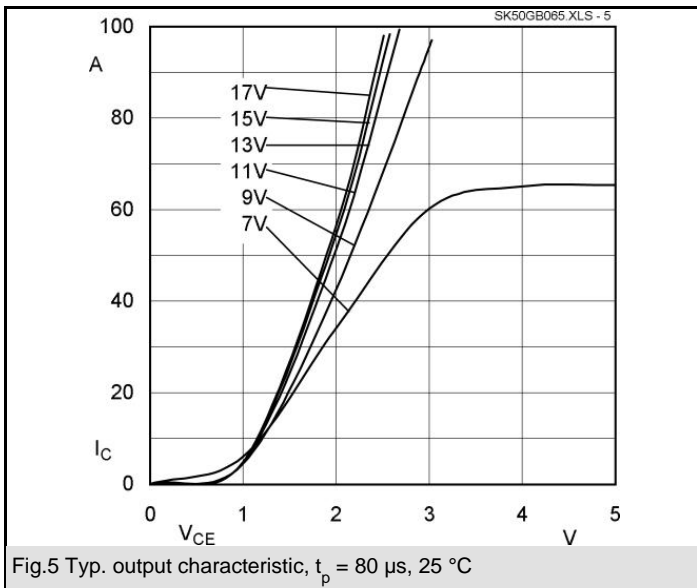
- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS

Absolute Maximum Ratings		T _s = 25 °C, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT			
V _{CES}		600	V
V _{GES}		± 20	V
I _C	T _s = 25 (80) °C;	54 (40)	A
I _{CM}	t _p < 1 ms; T _s = 25 (80) °C;	108 (80)	A
T _j		- 40 ... + 150	°C
Inverse/Freewheeling CAL diode			
I _F	T _s = 25 (80) °C;	64 (48)	A
I _{FM} = - I _{CM}	t _p < 1 ms; T _s = 25 (80) °C;	124 (96)	A
T _j		- 40 ... + 150	°C
T _{stg}		- 40 ... + 125	°C
T _{sol}	Terminals, 10 s	260	°C
V _{isol}	AC 50 Hz, r.m.s. 1 min. / 1 s	2500 / 3000	V

Characteristics		T _s = 25 °C, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT					
V _{CE(sat)}	I _C = 40 A, T _j = 25 (125) °C		1,7 (2,2)	2 (2,2)	V
V _{GE(th)}	V _{CE} = V _{GE} ; I _C = 0,0014 A	4,5	5,5	6,5	V
C _{ies}	V _{CE} = 25 V; V _{GE} = 0 V; 1 MHz		3		nF
R _{th(j-s)}	per IGBT per module			0,85	K/W K/W
under following conditions:					
t _{d(on)}	V _{CC} = 300 V, V _{GE} = ± 15 V		60	80	ns
t _r	I _C = 40 A, T _j = 125 °C		30	40	ns
t _{d(off)}	R _{Gon} = R _{Goff} = 16 Ω		220	280	ns
t _f			20	26	ns
E _{on} + E _{off}	Inductive load		1,8	2,4	mJ
Inverse/Freewheeling CAL diode					
V _F = V _{EC}	I _F = 50 A; T _j = 25 (125) °C		1,45 (1,4)	1,7 (1,75)	V
V _(TO)	T _j = (125) °C		(0,85)	(0,9)	V
r _T	T _j = (125) °C		(11)	(16)	mΩ
R _{th(j-s)}				1,1	K/W
under following conditions:					
I _{RRM}	I _F = 50 A; V _R = 300 V		40		A
Q _{rr}	di _F /dt = -1000 A/μs		3,6		μC
E _{off}	V _{GE} = 0 V; T _j = 125 °C		0,55		mJ
Mechanical data					
M1	mounting torque			2	Nm
w			19		g
Case	SEMITOP® 2		T 32		



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